

RELIABILITY REPORT

FOR

MAX6195BESA+ (MAX6190-MAX6195/MAX6198)

PLASTIC ENCAPSULATED DEVICES

March 5, 2009

# **MAXIM INTEGRATED PRODUCTS**

120 SAN GABRIEL DR. SUNNYVALE, CA 94086

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### Conclusion

The MAX6195BESA+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim"s continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim"s quality and reliability standards.

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# I. Device Description

#### A. General

The MAX6190-MAX6198 precision, micro-power, low-dropout voltage references offer high initial accuracy and very low temperature coefficient through a proprietary curvature-correction circuit and laser-trimmed precision thin-film resistors. These series-mode bandgap references draw a maximum of only 35µA quiescent supply current, making them ideal for battery-powered instruments. They offer a supply current that is virtually immune to input voltage variations. Load-regulation specifications are guaranteed for source and sink currents up to 500µA. These devices are internally compensated, making them ideal for applications that require fast settling, and are stable with capacitive loads up to 2.2nF.



## II. Manufacturing Information

A. Description/Function: Precision, Micropower, Low-Dropout Voltage References

B. Process: B12

C. Number of Device Transistors:

D. Fabrication Location: Oregon

E. Assembly Location: ATP Philippines, UTL Thailand, Carsem Malaysia, Unisem Malaysia

F. Date of Initial Production: November 06, 1998

### III. Packaging Information

A. Package Type: 8-pin SOIC (N)
B. Lead Frame: Copper

C. Lead Finish:

Die Attach:

84-1Imisr4 Epoxy

E. Bondwire:

Gold (1.3 mil dia.)

F. Mold Material:

G. Assembly Diagram:

#05-0901-0152

H. Flammability Rating:

Class UL94-V0

I. Classification of Moisture Sensitivity per Level 1

JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: 170°C/W
K. Single Layer Theta Jc: 40°C/W
L. Multi Layer Theta Ja: 136°C/W
M. Multi Layer Theta Jc: 38°C/W

#### IV. Die Information

A. Dimensions: 44 X 31 mils

B. Passivation: Si<sub>3</sub>N<sub>4</sub>/SiO<sub>2</sub> (Silicon nitride/ Silicon dioxide

C. Interconnect: Aluminum/Si (Si = 1%)

D. Backside Metallization: None

E. Minimum Metal Width: 1.2 microns (as drawn)F. Minimum Metal Spacing: 1.2 microns (as drawn)

G. Bondpad Dimensions: 5 mil. Sq.
 H. Isolation Dielectric: SiO<sub>2</sub>
 I. Die Separation Method: Wafer Saw



## V. Quality Assurance Information

A. Quality Assurance Contacts: Ken Wendel (Director, Reliability Engineering)

Bryan Preeshl (Managing Director of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm</li>D. Sampling Plan: Mil-Std-105D

### VI. Reliability Evaluation

#### A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate ( $\lambda$ ) is calculated as follows:

$$\lambda = 1 \over \text{MTTF}$$
 =  $\frac{1.83}{192 \times 4340 \times 80 \times 2}$  (Chi square value for MTTF upper limit) (Chi square value for MTTF upper limit) (where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$x = 13.4 \times 10^{-9}$$

% = 13.4 F.I.T. (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly 1000 hour life test monitors on its processes. This data is published in the Product Reliability Report found at http://www.maxim-ic.com/. Current monitor data for the B8 Process results in a FIT Rate of 2.71 @ 25C and 17.30 @ 55C (0.8 eV, 60% UCL)

#### B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

### C. E.S.D. and Latch-Up Testing

The RF23-4 die type has been found to have all pins able to withstand a HBM transient pulse of +/-1500 V per Mil-Std 883 Method 3015.7. Latch-Up testing has shown that this device withstands a current of +/-250 mA.



## Table 1

# Reliability Evaluation Test Results

# MAX6195BESA+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test (	(Note 1)				
	Ta = 135°C Biased	DC Parameters & functionality	80	0	
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
85/85	Ta = 85°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 1000hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010				

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data